OMRON **MOS FET Relays**

G3VM-61H1

New MOS FET Relay Designed for **Switching Minute Signals and Analog** Signals Has a 6-pin SOP Package and 60-V Load Voltage

- Continuous load current of 400 mA.
- Dielectric strength of 1,500 Vrms between I/O.

Application Examples

- · Broadband systems
- · Measurement devices
- Data loggers
- Amusement machines

■List of Models





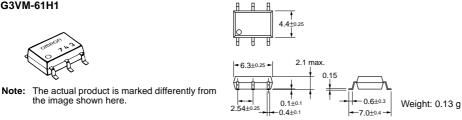
Note: The actual product is marked differently from the image shown here.

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	60 VAC	G3VM-61H1	75	
	terminals		G3VM-61H1(TR)		2,500

Dimensions

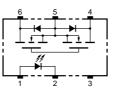
Note: All units are in millimeters unless otherwise indicated.

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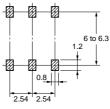
Terminal Arrangement/Internal Connections (Top View)

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■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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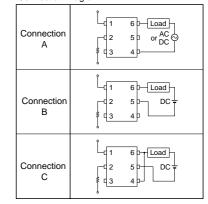


■ Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		١ _F	50	mA	
	Repetitive peak LED forward current		I _{FP}	1	A	100 μs pulses, 100 pps
	LED forward current reduction rate		$\Delta I_{F}^{\circ}C$	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage		V _R	5	V	
	Connection temperature		Тj	125	°C	
Output	Output dielectric strength		V _{OFF}	60	V	
	Continuous load current	Connection A	I _O	400	mA	
		Connection B	-	400	1	
		Connection C		800	1	
	ON current reduction rate	Connection A	∆ I _{ON} /°C	-4.0	mA/°C	Ta ≥ 25°C
		Connection B		-4.0		
		Connection C		-8.0		
	Connection temperature		Тj	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	1,500	Vrms	AC for 1 min	
Operating temperature			Ta	-40 to +85	°C	With no icing or condensation
Storage temperature			T _{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)				260	°C	10 s

Note:

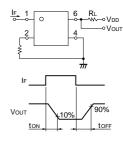
 The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side. Connection Diagram



■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions		
Input LED forward voltage Reverse current		V _F	1.0	1.15	1.3	V	I _F = 10 mA		
		current				10	μA	V _R = 5 V	
	Capacity between tern	ninals	CT		30		pF	V = 0, f = 1 MHz	
Trigger LED forward curre		urrent	I _{FT}		1.6	3	mA	I _O = 400 mA	
Output	Maximum resistance with output ON	Connection A	R _{ON}		1	2	Ω	I _F = 5 mA, I _O = 400 mA	
		Connection B			0.5	1	Ω	I _F = 5 mA, I _O = 400 mA	
		Connection C			0.25		Ω	I _F = 5 mA, I _O = 800 mA	
Current leakage when the relay is open		I _{LEAK}			1.0	μA	V _{OFF} = 60 V		
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V		
Insulation resistance		R _{I-O}	1,000			MΩ	$\label{eq:VI-O} \begin{array}{l} V_{I\text{-}O} = 500 \ \text{VDC}, \\ \text{RoH} \leq 60\% \end{array}$		
Turn-ON time		tON		0.8	2.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$		
Turn-OF	Turn-OFF time		tOFF		0.1	0.5	ms	V _{DD} = 20 V (See note 2.)	





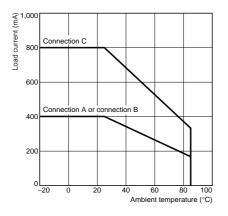
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			48	V
Operating LED forward current	IF	5	7.5	25	mA
Continuous load current	I _O			400	mA
Operating temperature	Ta	- 20		65	°C

Engineering Data

Load Current vs. Ambient Temperature G3VM-61H1



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.